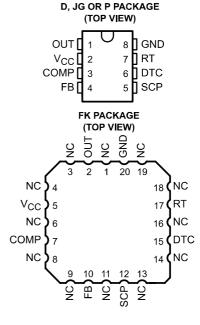
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- **Complete PWM Power Control**
- 3.6-V to 40-V Operation
- Internal Undervoltage-Lockout Circuit
- Internal Short-Circuit Protection
- Oscillator Frequency . . . 20 kHz to 500 kHz
- **Variable Dead Time Provides Control Over Total Range**
- ±3% Tolerance on Reference Voltage (TL5001A)
- Available in Q-Temp Automotive **HighRel Automotive Applications Configuration Control / Print Support Qualification to Automotive Standards**

description

The TL5001 and TL5001A incorporate on a single monolithic chip all the functions required for a pulse-width-modulation (PWM) control circuit. Designed primarily for power-supply control, the TL5001/A contains an error amplifier, a regulator, an oscillator, a PWM comparator with a dead-time-conundervoltage trol input,



(UVLO), short-circuit protection (SCP), and an open-collector output transistor. The TL5001A has a typical reference voltage tolerance of $\pm 3\%$ compared to $\pm 5\%$ for the TL5001.

The error-amplifier common-mode voltage ranges from 0 V to 1.5 V. The noninverting input of the error amplifier is connected to a 1-V reference. Dead-time control (DTC) can be set to provide 0% to 100% dead time by connecting an external resistor between DTC and GND. The oscillator frequency is set by terminating RT with an external resistor to GND. During low V_{CC} conditions, the UVLO circuit turns the output off until V_{CC} recovers to its normal operating range.

The TL5001C and TL5001AC are characterized for operation from -20°C to 85°C. The TL5001I and TL5001AI are characterized for operation from -40°C to 85°C. The TL5001Q and TL5001AQ are characterized for operation from -40°C to 125°C. The TL5001M and TL5001AM are characterized for operation from -55°C to 125°C.

AVAILABLE OPTIONS

		PACKAGED	DEVICES	
TA	SMALL OUTLINE (D)	PLASTIC DIP (P)	CERAMIC DIP (JG)	CHIP CARRIER (FK)
-20°C to 85°C	TL5001CD	TL5001CP	1	_
-20 C to 65 C	TL5001ACD	TL5001ACP	_	_
-40°C to 85°C	TL5001ID	TL5001IP	-	_
-40 C to 65 C	TL5001AID	TL5001AIP	1	
-40°C to 125°C	TL5001QD	1	_	_
-40 C to 125 C	TL5001AQD	1	1	
-55°C to 125°C	_		TL5001MJG	TL5001MFK
-55 C to 125 C	_		TL5001AMJG	TL5001AMFK

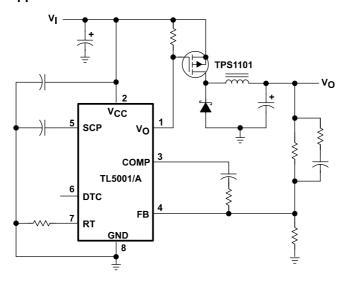
The D package is available taped and reeled. Add the suffix R to the device type (e.g., TL5001CDR).



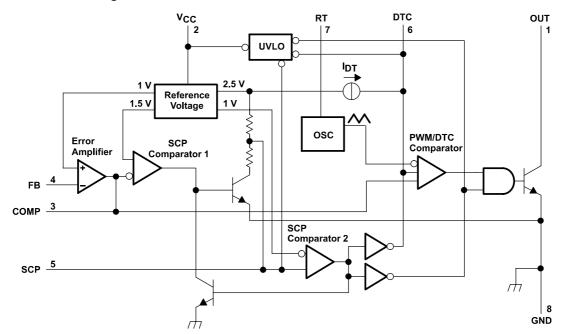
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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schematic for typical application



functional block diagram



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detailed description

voltage reference

A 2.5-V regulator operating from V_{CC} is used to power the internal circuitry of the TL5001 and TL5001A and as a reference for the error amplifier and SCP circuits. A resistive divider provides a 1-V reference for the error amplifier noninverting input which typically is within 2% of nominal over the operating temperature range.

error amplifier

The error amplifier compares a sample of the dc-to-dc converter output voltage to the 1-V reference and generates an error signal for the PWM comparator. The dc-to-dc converter output voltage is set by selecting the error-amplifier gain (see Figure 1), using the following expression:

$$V_0 = (1 + R1/R2) (1 V)$$

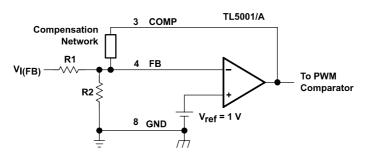


Figure 1. Error-Amplifier Gain Setting

The error-amplifier output is brought out as COMP for use in compensating the dc-to-dc converter control loop for stability. Because the amplifier can only source 45 μ A, the total dc load resistance should be 100 k Ω or more.

oscillator/PWM

The oscillator frequency (f_{OSC}) can be set between 20 kHz and 500 kHz by connecting a resistor between RT and GND. Acceptable resistor values range from 15 k Ω to 250 k Ω . The oscillator frequency can be determined by using the graph shown in Figure 5.

The oscillator output is a triangular wave with a minimum value of approximately 0.7 V and a maximum value of approximately 1.3 V. The PWM comparator compares the error-amplifier output voltage and the DTC input voltage to the triangular wave and turns the output transistor off whenever the triangular wave is greater than the lesser of the two inputs.

dead-time control (DTC)

DTC provides a means of limiting the output-switch duty cycle to a value less than 100 %, which is critical for boost and flyback converters. A current source generates a reference current (I_{DT}) at DTC that is nominally equal to the current at the oscillator timing terminal, RT. Connecting a resistor between DTC and GND generates a dead-time reference voltage (V_{DT}), which the PWM/DTC comparator compares to the oscillator triangle wave as described in the previous section. Nominally, the maximum duty cycle is 0 % when V_{DT} is 0.7 V or less and 100 % when V_{DT} is 1.3 V or greater. Because the triangle wave amplitude is a function of frequency and the source impedance of RT is relatively high (1250 Ω), choosing R_{DT} for a specific maximum duty cycle, D, is accomplished using the following equation and the voltage limits for the frequency in question as found in Figure 11 (V_{OSC} max and V_{OSC} min are the maximum and minimum oscillator levels):



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dead-time control (DTC) (continued)

$$R_{DT} = (R_t + 1250) [D(V_{osc}max - V_{osc}min) + V_{osc}min]$$

Where

RDT and Rt are in ohms, D in decimal

Soft start can be implemented by paralleling the DTC resistor with a capacitor (C_{DT}) as shown in Figure 2. During soft start, the voltage at DTC is derived by the following equation:

Figure 2. Soft-Start Circuit

If the dc-to-dc converter must be in regulation within a specified period of time, the time constant, $R_{DT}C_{DT}$, should be $t_0/3$ to $t_0/5$. The TL5001/A remains off until $V_{DT} \approx 0.7$ V, the minimum ramp value. C_{DT} is discharged every time UVLO or SCP becomes active.

undervoltage-lockout (UVLO) protection

The undervoltage-lockout circuit turns the output transistor off and resets the SCP latch whenever the supply voltage drops too low (approximately 3 V at 25°C) for proper operation. A hysteresis voltage of 200 mV eliminates false triggering on noise and chattering.

short-circuit protection (SCP)

The TL5001/A includes short-circuit protection (see Figure 3), which turns the power switch off to prevent damage when the converter output is shorted. When activated, the SCP prevents the switch from being turned on until the internal latching circuit is reset. The circuit is reset by reducing the input voltage until UVLO becomes active or until the SCP terminal is pulled to ground externally.

When a short circuit occurs, the error-amplifier output at COMP rises to increase the power-switch duty cycle in an attempt to maintain the output voltage. SCP comparator 1 starts an RC timing circuit when COMP exceeds 1.5 V. If the short is removed and the error-amplifier output drops below 1.5 V before time out, normal converter operation continues. If the fault is still present at the end of the time-out period, the timer sets the latching circuit and turns off the TL5001/A output transistor.



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short-circuit protection (SCP) (continued)

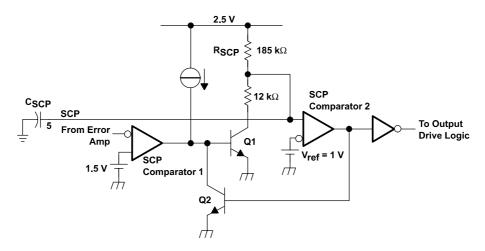


Figure 3. SCP Circuit

The timer operates by charging an external capacitor (C_{SCP}), connected between the SCP terminal and ground, towards 2.5 V through a 185-k Ω resistor (R_{SCP}). The circuit begins charging from an initial voltage of approximately 185 mV and times out when the capacitor voltage reaches 1 V. The output of SCP comparator 2 then goes high, turns on Q2, and latches the timer circuit. The expression for setting the SCP time period is derived from the following equation:

$$V_{SCP} = (2.5 - 0.185)(1 - e^{-t/\tau}) + 0.185$$

Where

$$\tau = R_{SCP}C_{SCP}$$

The end of the time-out period, t_{SCP} , occurs when $V_{SCP} = 1 \text{ V. Solving for } C_{SCP}$ yields:

$$C_{SCP} = 12.46 \times t_{SCP}$$

Where

t is in seconds, C in $\mu\text{F}.$

t_{SCP} must be much longer (generally 10 to 15 times) than the converter start-up period or the converter will not start.

output transistor

The output of the TL5001/A is an open-collector transistor with a maximum collector current rating of 21 mA and a voltage rating of 51 V. The output is turned on under the following conditions: the oscillator triangle wave is lower than both the DTC voltage and the error-amplifier output voltage, the UVLO circuit is inactive, and the short-circuit protection circuit is inactive.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted) †

Supply voltage, V _{CC} (see Note 1) Amplifier input voltage, V _{I(FB)} Output voltage, V _O , OUT		20 V
Output current, I _O , OUT		
Output peak current, I _{O(peak)} , OUT Continuous total power dissipation		See Dissipation Rating Table
Operating ambient temperature range, T _A :		
,	TL5001I, TL5001AI	–40°C to 85°C
	TL5001Q, TL5001AQ	–40°C to 125°C
	TL5001M, TL5001AM	–55°C to 125°C
Storage temperature range, T _{stq}		
Lead temperature 1,6 mm (1/16 inch) from	case for 10 seconds	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to network ground terminal.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{$\Delta$}} \le 25^{\circ}\mbox{$C$}$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW
FK	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW
Р	1000 mW	8.0 mW/°C	640 mW	520 mW	200 mW

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V _{CC}		3.6	40	V
Amplifier input voltage, V _{I(FB)}		0	1.5	V
Output voltage, V _O , OUT			50	V
Output current, IO, OUT			20	mA
COMP source current			45	μΑ
COMP dc load resistance		100		kΩ
Oscillator timing resistor, R _t		15	250	kΩ
Oscillator frequency, fosc		20	500	kHz
	TL5001C, TL5001AC	-20	85	
Operating ambient temperature T	TL5001I, TL5001AI	-40	85	°c
Operating ambient temperature, T _A	TL5001Q, TL5001AQ	-40	125	
	TL5001M, TL5001AM	-55	125	1



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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 6 V, f_{osc} = 100 kHz (unless otherwise noted)

reference

PARAMETER	TEST CONDITIONS	TL5001C, TL5001I			TL5001AC, TL5001AI			UNIT
PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	MIN	TYP [†]	MAX	ONIT
Output voltage	COMP connected to FB	0.95	1	1.05	0.97	1	1.03	V
Input regulation	V _{CC} = 3.6 V to 40 V		2	12.5		2	12.5	mV
	$T_A = -20^{\circ}C$ to 25°C (C suffix)	-10	-1	10	-10	-1	10	
Output voltage change with temperature	$T_A = -40^{\circ}C$ to 25°C (I suffix)	-10	-1	10	-10	-1	10	mV/V
	T _A = 25°C to 85°C	-10	-2	10	-10	-2	10	

[†] All typical values are at T_A = 25°C.

undervoltage lockout

PARAMETER	TEST CONDITIONS		TL5001C, TL5001I			TL5001AC, TL5001AI			
PARAMETER	TEST CONDITIONS	MIN	TYP [†]	MAX	MIN	TYP†	MAX	UNIT	
Upper threshold voltage	T _A = 25°C		3			3		V	
Lower threshold voltage	T _A = 25°C		2.8			2.8		V	
Hysteresis	T _A = 25°C	100	200		100	200		mV	
Reset threshold voltage	T _A = 25°C	2.1	2.55		2.1	2.55		V	

[†] All typical values are at T_A = 25°C.

short-circuit protection

PARAMETER	TEST CONDITIONS	TL50	01C, TL5	i001I	TL5001	UNIT		
PARAIMETER	TEST CONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
SCP threshold voltage	T _A = 25°C	0.95	1.00	1.05	0.97	1.00	1.03	V
SCP voltage, latched	No pullup	140	185	230	140	185	230	mV
SCP voltage, UVLO standby	No pullup		60	120		60	120	mV
Input source current	T _A = 25°C	- 10	– 15	- 20	-10	-15	- 20	μΑ
SCP comparator 1 threshold voltage			1.5			1.5		V

[†] All typical values are at T_A = 25°C.

oscillator

PARAMETER	TEST CONDITIONS	TL50	01C, TL5	001I	TL500	IAC, TL5	5001AI	UNIT
PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
Frequency	$R_t = 100 \text{ k}\Omega$		100			100		kHz
Standard deviation of frequency			15			15		kHz
Frequency change with voltage	V_{CC} = 3.6 V to 40 V		1			1		kHz
	$T_A = -40$ °C to 25°C	-4	-0.4	4	-4	-0.4	4	kHz
Frequency change with temperature	$T_A = -20^{\circ}C \text{ to } 25^{\circ}C$	-4	-0.4	4	-4	-0.4	4	kHz
	T _A = 25°C to 85°C	-4	-0.2	4	-4	-0.2	4	kHz
Voltage at RT			1			1		V

[†] All typical values are at $T_A = 25$ °C.



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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 6 V, f_{osc} = 100 kHz (unless otherwise noted) (continued)

dead-time control

PARAMETER		TEST CONDITIONS	TL5001C, TL5001I			TL5001.	UNIT		
PARAMETER		TEST CONDITIONS	MIN	TYP [†]	MAX	MIN	TYP†	MAX	ONIT
Output (course) augment	TL5001C	V _(DT) = 1.5 V	0.9 × I _{RT} ‡		1.1 × I _{RT}	0.9 × I _{RT} ‡		$1.1 \times I_{RT}$	^
Output (source) current	TL5001I	V _(DT) = 1.5 V	$0.9 \times I_{RT}^{\ddagger}$		$1.2 \times I_{RT}$	$0.9 \times I_{RT}^{\ddagger}$		1.2 × I _{RT}	μΑ
Input threshold voltage		Duty cycle = 0%	0.5	0.7		0.5	0.7		V
Input threshold voltage		Duty cycle = 100%		1.3	1.5		1.3	1.5	V

[†] All typical values are at T_A = 25°C. ‡ Output source current at RT

error amplifier

PARAMETER		TEST CONDITIONS	TL5001C, TL5001I			TL500	UNIT		
FANAMETER		TEST CONDITIONS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNII
Input voltage		V _{CC} = 3.6 V to 40 V	0		1.5	0		1.5	V
Input bias current				-160	-500		-160	-500	nA
Positive			1.5	2.3		1.5	2.3		V
Output voltage swing	Negative			0.3	0.4		0.3	0.4	V
Open-loop voltage amplification				80			80		dB
Unity-gain bandwidth				1.5			1.5		MHz
Output (sink) current		V _{I(FB)} = 1.2 V, COMP = 1 V	100	600		100	600		μΑ
Output (source) current		V _{I(FB)} = 0.8 V, COMP = 1 V	-45	-70		-45	- 70		μА

[†] All typical values are at T_A = 25°C.

output

PARAMETER	TEST CONDITIONS	TL5001C, TL	TL5001C, TL5001I			TL5001AC, TL5001AI		
PARAMETER	TEST CONDITIONS	MIN TYPT	MAX	MIN	TYP†	MAX	UNIT	
Output saturation voltage	I _O = 10 mA	1.5	2		1.5	2	V	
Off-state current	$V_{O} = 50 \text{ V}, \qquad V_{CC} = 0$		10			10	4	
	V _O = 50 V		10			10	μΑ	
Short-circuit output current	V _O = 6 V	40			40		mA	

[†] All typical values are at T_A = 25°C.

total device

PARAMETER		TEST CONDITIONS	TL50	01C, TL5	001I	TL5001AC, TL5001AI			UNIT
PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
Standby supply current	Off state			1	1.5		1	1.5	mA
Average supply current		$R_t = 100 \text{ k}\Omega$		1.4	2.1		1.4	2.1	mA

[†] All typical values are at T_A = 25°C.



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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 6 V, f_{osc} = 100 kHz (unless otherwise noted)

reference

PARAMETER	TEST	TEST CONDITIONS					L5001AG L5001AN	/	UNIT
			MIN	TYP [†]	MAX	MIN	TYP†	MAX	
Output voltage	T _A = 25°C	COMP connected to FB	0.95	1.00	1.05	0.97	1.00	1.03	V
Output voltage	$T_A = MIN \text{ to MAX}$	COMP connected to PB	0.93	0.98	1.07	0.94	0.98	1.06	V
Input regulation	$T_A = MIN \text{ to MAX}$	V _{CC} = 3.6 V to 40 V		2	12.5		2	12.5	mV
Output voltage change with temperature	T _A = MIN to MAX		*-6	2	*6	*-6	2	*6	%

[†] All typical values are at T_A = 25°C. *Not production tested.

undervoltage lockout

PARAMETER	TEST CONDITIONS		L5001Q L5001M		TI T	UNIT		
		MIN	TYP [†]	MAX	MIN	TYP†	MAX	
Upper threshold voltage	T _A = MIN, 25°C		3.00			3.00		V
pper threshold voltage	$T_A = MAX$		2.55			2.55		V
Lower threshold voltage	T _A = MIN, 25°C	= MIN, 25°C 2.8						V
Lower threshold voltage	$T_A = MAX$		2.0			2.0		v
Hysteresis	$T_A = MIN \text{ to } MAX$	100	200		100	200		mV
Boost throughold voltage	T _A = MIN, 25°C	2.10	2.55		2.10	2.55		V
Reset threshold voltage	$T_A = MAX$	0.35	0.63		0.35	0.63		l ^v

[†] All typical values are at T_A = 25°C.

short-circuit protection

PARAMETER	TEST CO	TEST CONDITIONS			,	TI T	UNIT		
			MIN	TYP†	MAX	MIN	TYP†	MAX	
SCD throughold voltage	T _A = MIN, 25°C		0.95	1.00	1.05	0.97	1.00	1.03	V
SCP threshold voltage	T _A = MAX	0.93	0.98	1.07	0.94	0.98	1.06	V	
SCP voltage, latched	T _A = MIN to MAX	No pullup	140	185	230	140	185	230	mV
SCP voltage, UVLO standby	T _A = MIN to MAX	No pullup		60	120		60	120	mV
Equivalent timing resistance	T _A = MIN to MAX			185			185		kΩ
SCP comparator 1 threshold voltage	T _A = MIN to MAX			1.5			1.5		V

[†] All typical values are at T_A = 25°C.



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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 6 V, f_{osc} = 100 kHz (unless otherwise noted) (continued)

oscillator

PARAMETER	TEST C	TEST CONDITIONS				TI T	UNIT		
						MIN	TYP†	MAX	
Frequency	T _A = MIN to MAX	R_t = 100 k Ω		100			100		kHz
Standard deviation of frequency	T _A = MIN to MAX			2			2		kHz
Frequency change with voltage	T _A = MIN to MAX	V _{CC} = 3.6 V to 40 V		1			1		kHz
Frequency change with	T MINIA- MAY	Q suffix	*-6	3	*6	*-6	3	*6	kHz
temperature	IA = MIN to MAX	T _A = MIN to MAX M suffix		5	*9	*-9	5	*9	KHZ
Voltage at RT	T _A = MIN to MAX	T _A = MIN to MAX		1			1		V

[†] All typical values are at T_A = 25°C. *Not production tested.

dead-time control

PARAMETER	TEST C	ONDITIONS	TL500	1Q, TL50	001M	TL5001/	UNIT		
PARAMETER	1231 C		MIN	TYP [†]	MAX	MIN	TYP†	MAX	UNIT
Output (source) current	$T_A = MIN \text{ to } MAX$	V _(DT) = 1.5 V	0.9×I _{RT} ‡		1.1 × I _{RT}	0.9 × I _{RT} ‡		1.1 × I _{RT}	μΑ
T - 0500		Duty cycle = 0%	0.5	0.7		0.5	0.7		
Input threshold	T _A = 25°C	Duty cycle = 100%		1.3	1.5		1.3	1.5	V
voltage	T _A = MIN to MAX	Duty cycle = 0%	0.4	0.7		0.4	0.7		V
	IA – MIIN 10 MAX	Duty cycle = 100%		1.3	1.7		1.3	1.7	

[†] All typical values are at T_A = 25°C. ‡ Output source current at RT

error amplifier

PARAMETER TEST CONDITIONS					L5001Q L5001M		TI T		UNIT		
					MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	
Input bias current		T _A = MIN to MAX				-160	-500		-160	-500	nA
Output voltage	Positive	T _A = MIN to MAX			1.5	2.3		1.5	2.3		V
swing	Negative	IA - MIIN TO MAX				0.3	0.4		0.3	0.4	V
Open-loop voltage amplification		T _A = MIN to MAX				80			80		dB
Unity-gain bandwidth		T _A = MIN to MAX				1.5			1.5		MHz
Output (sink) current		T _A = MIN to MAX	$V_{I(FB)} = 1.2 V$,	COMP = 1 V	100	600		100	600		μΑ
Output (agurag) gurag	T _A = MIN, 25°C		V _{I/FB}) = 0.8 V. COMP = 1 V		- 45	– 70		- 45	- 70		
Output (source) current TA = MAX	$V_{I(FB)} = 0.8 \text{ V}, \text{ COMP} = 1$		-30	- 45		-30	-45		μΑ		

[†] All typical values are at T_A = 25°C.



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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 6 V, f_{osc} = 100 kHz (unless otherwise noted) (continued)

output

PARAMETER	TEST	CONDITIONS	1	TL5001Q TL5001M		TI T	UNIT		
			MIN	TYP [†]	MAX	MIN	TYP†	MAX	
Output saturation voltage	$T_A = MIN \text{ to MAX}$	I _O = 10 mA		1.5	2		1.5	2	V
Off-state current	T MIN to MAX	$V_O = 50 \text{ V}, V_{CC} = 0$			10			10	
On-state current	$T_A = MIN \text{ to MAX}$	V _O = 50 V			10			10	μΑ
Short-circuit output current	$T_A = MIN \text{ to MAX}$	V _O = 6 V		40			40		mΑ

[†] All typical values are at T_A = 25°C.

total device

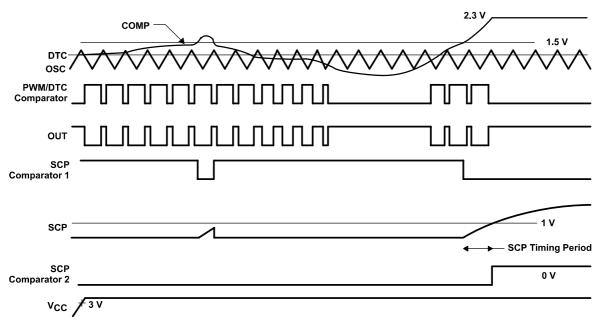
PARAMETER		TEST CON	TEST CONDITIONS				TI Ti	UNIT		
		MIN	TYP†	MAX	MIN	TYP†	MAX			
Standby supply current	Off state	$T_A = MIN \text{ to } MAX$			1	1.5		1	1.5	mA
Average supply current		$T_A = MIN \text{ to } MAX$	$R_t = 100 \text{ k}\Omega$		1.4	2.1		1.4	2.1	mA

[†] All typical values are at T_A = 25°C.



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PARAMETER MEASUREMENT INFORMATION



NOTE A: The waveforms show timing characteristics for an intermittent short circuit and a longer short circuit that is sufficient to activate SCP.

Figure 4. PWM Timing Diagram



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TYPICAL CHARACTERISTICS

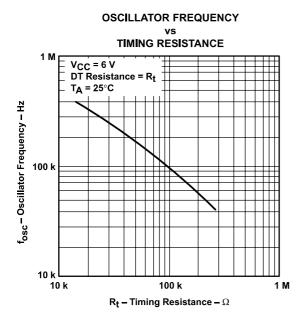


Figure 5

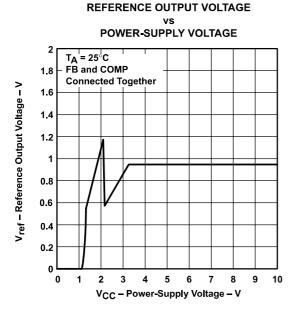


Figure 7

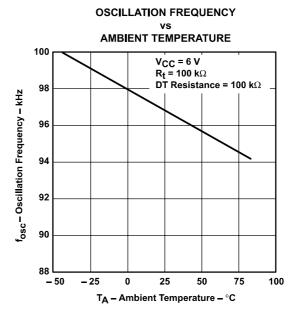


Figure 6

REFERENCE OUTPUT VOLTAGE FLUCTUATION vs AMBIENT TEMPERATURE 0.6 V_{CC} = 6 V

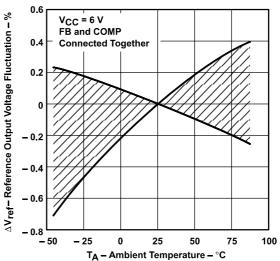


Figure 8

TYPICAL CHARACTERISTICS

Figure 9

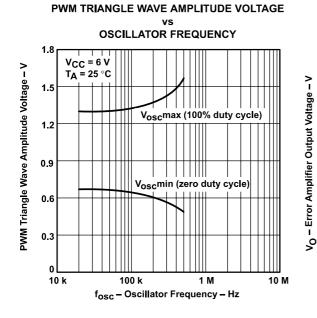


Figure 11

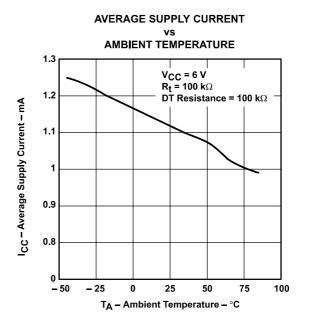


Figure 10

ERROR AMPLIFIER OUTPUT VOLTAGE vs OUTPUT (SINK) CURRENT

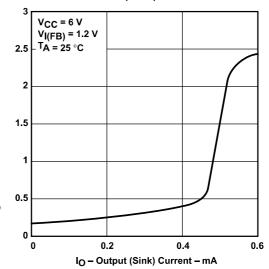


Figure 12

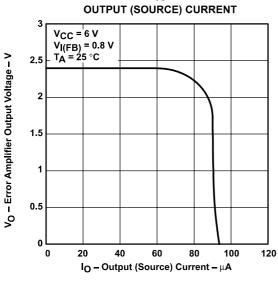


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TYPICAL CHARACTERISTICS

ERROR AMPLIFIER OUTPUT VOLTAGE OUTPUT (SOURCE) CURRENT V_{CC} = 6 V V_{I(FB)} = 0.8 V T_A = 25 °C V_O - Error Amplifier Output Voltage - V 1.5 0.5 0 80 120 60

Figure 13



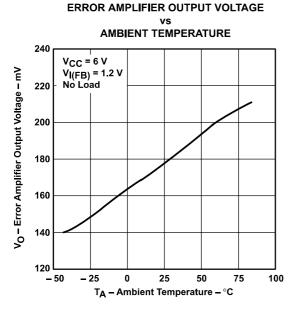


Figure 15

ERROR AMPLIFIER OUTPUT VOLTAGE AMBIENT TEMPERATURE V_{CC} = 6 V V_{I(FB)} = 0.8 V No Load V_O - Error Amplifier Output Voltage - V 2.45 2.44 2.43 2.42 2.41 2.40 **- 25** 0 25 50 75 100 T_A – Ambient Temperature – °C

Figure 14

ERROR AMPLIFIER OPEN-LOOP GAIN AND

PHASE SHIFT

FREQUENCY V_{CC} = 6 V T_A = 25 °C Error Amplifier Open-Loop Phase Shift -210° -240° -300°

Figure 16

f - Frequency - Hz

100 k



40

30

20

10

0

10

10 k

Ay - Error Amplifier Open-Loop Gain - dB

330°

—360° 10 M

TYPICAL CHARACTERISTICS

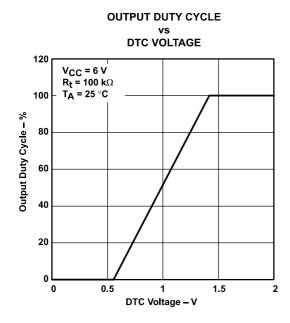


Figure 17

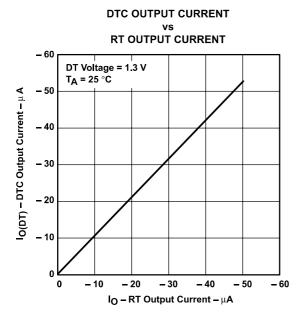


Figure 19

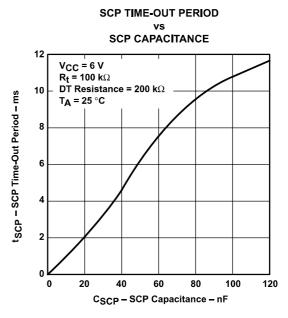


Figure 18

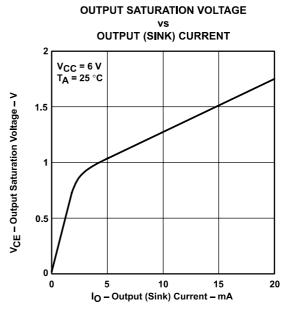


Figure 20



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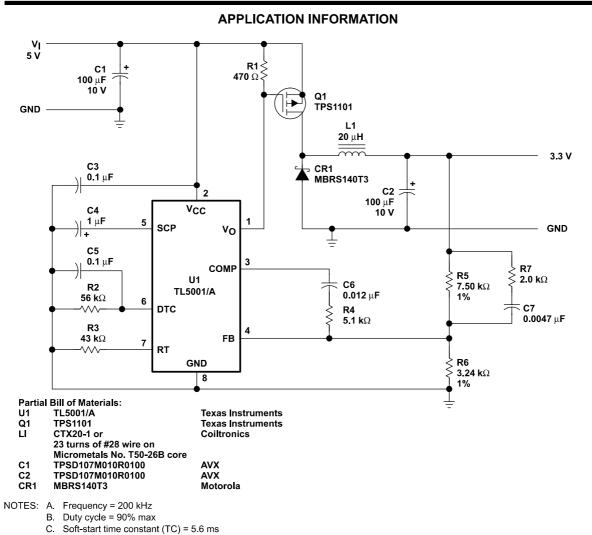


Figure 21. Step-Down Converter

D. SCP TC = 70 msA

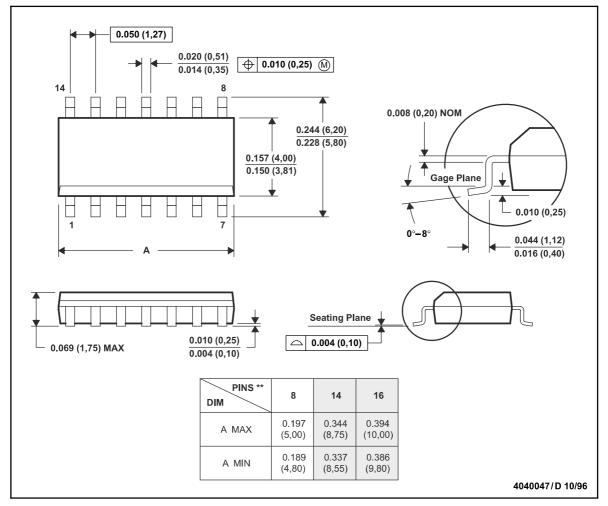
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MECHANICAL DATA

D (R-PDSO-G**)

14 PIN SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: B. All linear dimensions are in inches (millimeters).

C. This drawing is subject to change without notice.

D. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

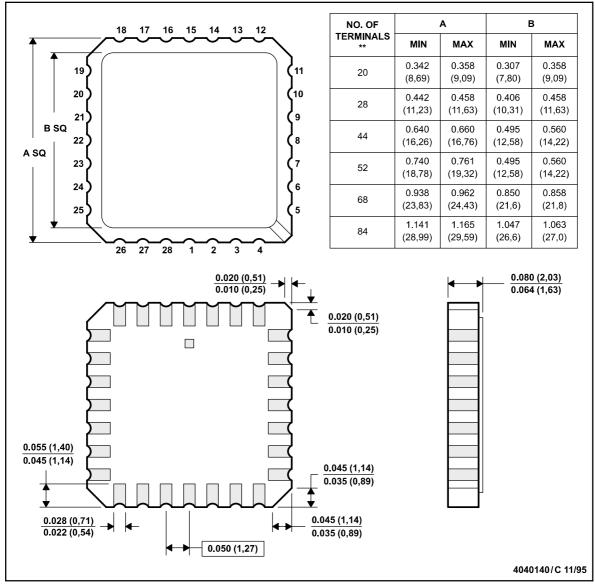
E. Falls within JEDEC MS-012

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MECHANICAL DATA

FK (S-CQCC-N**) 28 TERMINALS SHOWN

LEADLESS CERAMIC CHIP CARRIER



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. The terminals are gold-plated.
- E. Falls within JEDEC MS-004





PACKAGE OPTION ADDENDUM

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PACKAGING INFORMATION

Orderab	ole Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	n MSL Peak Temp ⁽³⁾
5962-99	58301Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-99	58301QPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
5962-99	58302Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-99	58302QPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
TL50	01ACD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL500	1ACDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL500)1ACDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL5001	ACDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL50	01ACP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TL500	1ACPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TL50	001AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL500	11AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL500	01AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL5001	1AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL50	001AIP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TL500	1AIPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TL500	1AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
TL500	1AMJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
TL500	1AMJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
TL50	01AQD	ACTIVE	SOIC	D	8	75	TBD	CU NIPDAU	Level-1-220C-UNLIM
TL500	1AQDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL500	1AQDR	ACTIVE	SOIC	D	8	2500	TBD	CU NIPDAU	Level-1-220C-UNLIM
TL5001	AQDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL50	001CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL500	01CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL50	01CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL500	1CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL50	001CP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TI 500	01CP-P	ACTIVE	PDIP	Р	8	50	Pb-Free	CU NIPDAU	N / A for Pkg Type



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Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
						(RoHS)		
TL5001CP-PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TL5001CPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TL5001CPS	ACTIVE	SO	PS	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL5001CPSG4	ACTIVE	SO	PS	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL5001CPSLE	OBSOLETE	SO	PS	8		TBD	Call TI	Call TI
TL5001CPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL5001CPSRG4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL5001ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL5001IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL5001IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL5001IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL5001IP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TL5001IPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TL5001MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
TL5001MJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
TL5001MJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
TL5001QD	ACTIVE	SOIC	D	8	75	TBD	CU NIPDAU	Level-1-220C-UNLIM
TL5001QDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL5001QDR	ACTIVE	SOIC	D	8	1	TBD	CU NIPDAU	Level-1-220C-UNLIM
TL5001QDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

 $^{^{(1)}}$ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered

rol air of substances, including the requirement that lead not exceed 0.1% by weight in honogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements



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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. – The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF TL5001, TL5001A, TL5001AM, TL5001M:

• Automotive: TL5001A-Q1

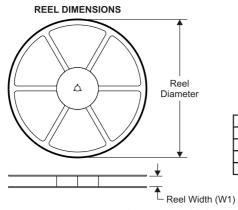
NOTE: Qualified Version Definitions:

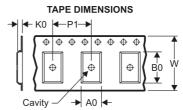
• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

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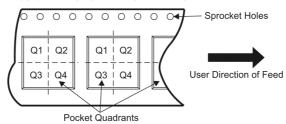
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

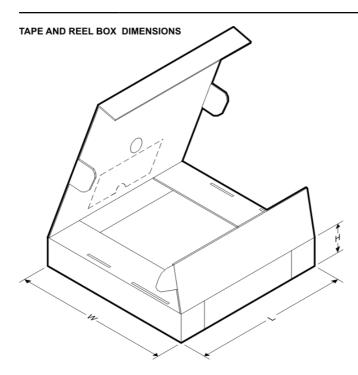


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL5001ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL5001AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL5001AQDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL5001CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL5001CPSR	so	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
TL5001IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL5001QDR	SOIC	D	8	1	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

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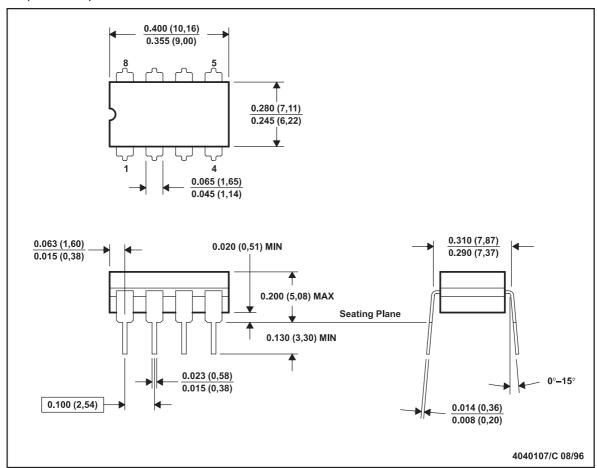


*All dimensions are nominal

, and difficulties and from the state of the							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL5001ACDR	SOIC	D	8	2500	340.5	338.1	20.6
TL5001AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TL5001AQDR	SOIC	D	8	2500	346.0	346.0	29.0
TL5001CDR	SOIC	D	8	2500	340.5	338.1	20.6
TL5001CPSR	SO	PS	8	2000	346.0	346.0	33.0
TL5001IDR	SOIC	D	8	2500	340.5	338.1	20.6
TL5001QDR	SOIC	D	8	1	346.0	346.0	29.0

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE



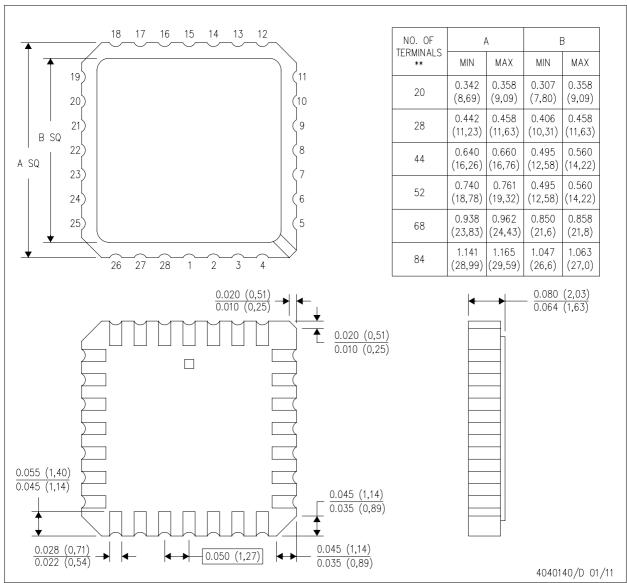
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
 E. Falls within MIL STD 1835 GDIP1-T8

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN

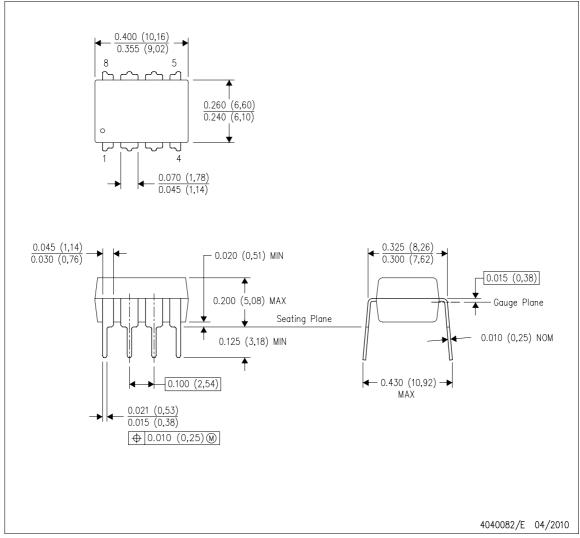


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



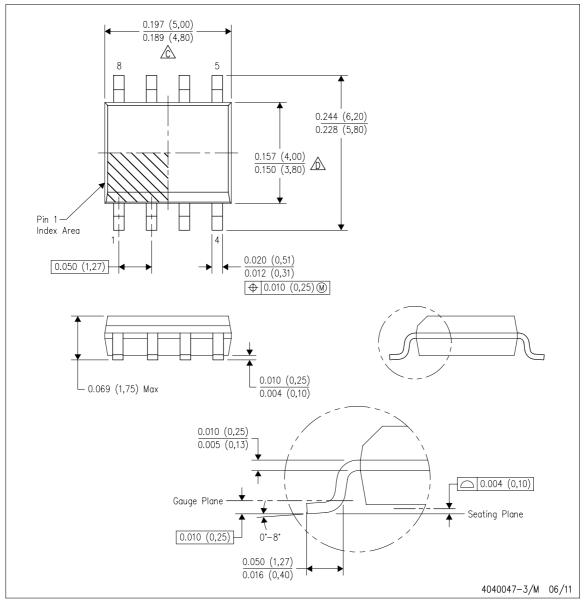
- A. All linear dimensions are in inches (millimeters).

 B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



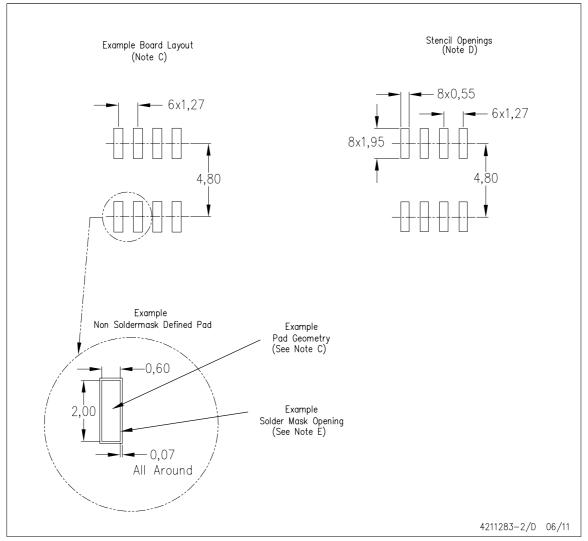
- All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.

 E. Reference JEDEC MS-012 variation AA.



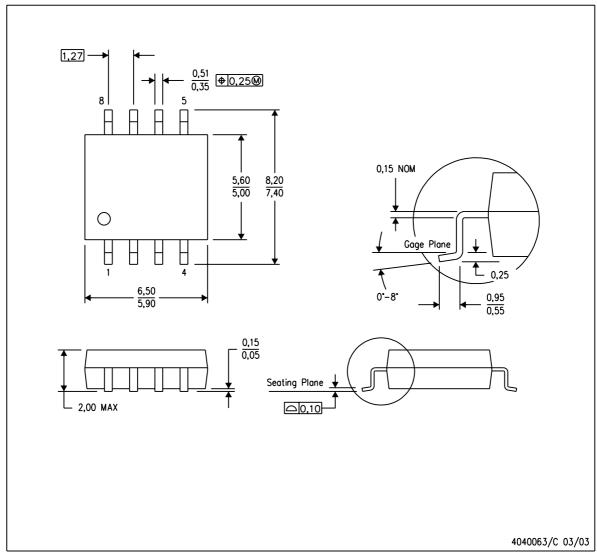
D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





NOTES:

All linear dimensions are in millimeters. This drawing is subject to change without notice. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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